NSN 5961-00-503-9342

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View Online at https://aerobasegroup.com/nsn/5961-00-503-9342 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 87.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 92220-t068-011 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: